



### DMT10H010LPS

# 100V N-CHANNEL ENHANCEMENT MODE MOSFET POWERDI

# **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> T <sub>C</sub> = +25°C	
100V	8.3mΩ @ V <sub>GS</sub> = 10V	98A	

### **Description**

This new generation N-Channel Enhancement Mode MOSFET is designed to minimize  $R_{DS(ON)}$ , yet maintain superior switching performance. This device is ideal for use in notebook battery power management and load switch.

### **Applications**

- Motor Control
- DC-DC Converters
- Power Management

### **Features**

- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low R<sub>DS(ON)</sub> Minimizes On-State Losses
- Low Input Capacitance
- · Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications</li>
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

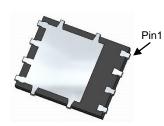
#### **Mechanical Data**

- Case: PowerDI5060-8
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminal Finish Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.097 grams (Approximate)

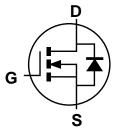
#### PowerDI5060-8



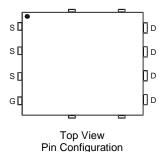
Top View



**Bottom View** 



Internal Schematic



#### **Ordering Information** (Note 4)

Part Number	Case	Packaging
DMT10H010LPS-13	PowerDI5060-8	2,500 / Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.



# **Marking Information**



T1010SS = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year
(ex: 15 = 2015)
WW = Week Code (01 to 53)

# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			$V_{DSS}$	100	V
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Operitoring Profes Comment V 40V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	I <sub>D</sub>	9.4 7.5	А
Continuous Drain Current V <sub>GS</sub> = 10V	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	I <sub>D</sub>	98 62	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I <sub>DM</sub>	100	Α
Maximum Continuous Body Diode Forward Current			I <sub>S</sub>	110	Α
Avalanche Current (Note 7), L=0.3mH			I <sub>AS</sub>	10	Α
Avalanche Energy (Note 7), L=0.3mH			E <sub>AS</sub>	15	mJ

# **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		$P_{D}$	1.2	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	99	°C/W
Total Power Dissipation	$T_{C} = +25^{\circ}C$	$P_{D}$	139	W
Thermal Resistance, Junction to Case	R <sub>0</sub> JC	0.9	°C/W	
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C	



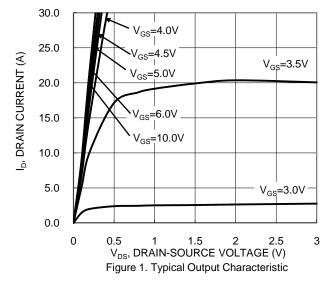
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	1	_	V	$V_{GS} = 0V$ , $I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	1	1	μΑ	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	1	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.4	1.9	3.0	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
		1	6.9	8.3		$V_{GS} = 10V, I_D = 13A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	-	7.5	12	mΩ	$V_{GS} = 6V, I_D = 13A$	
	, ,	_	10	20		$V_{GS} = 4.5V, I_D = 5A$	
Diode Forward Voltage	$V_{SD}$	_	8.0	1.3	V	$V_{GS} = 0V, I_{S} = 13A$	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	C <sub>iss</sub>	_	2592	_		\/ 50\/ \/ 0\/	
Output Capacitance	Coss	_	792	_	pF	$V_{DS} = 50V$ , $V_{GS} = 0V$ f = 1MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>		45	_		1 – 1101112	
Gate Resistance	$R_g$	_	2	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge	Qg	_	53.7	_		V 50V L 40A	
Gate-Source Charge	Q <sub>gs</sub>	_	10.6	_	nC	$V_{DD} = 50V, I_D = 13A,$	
Gate-Drain Charge	$Q_{gd}$	_	8.2	_		$V_{GS} = 10V$	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	11.6	_		V <sub>DD</sub> = 50V, V <sub>GS</sub> = 10V,	
Turn-On Rise Time	t <sub>R</sub>	_	14.1	_			
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	42.9	_	ns	$I_D = 13A$ , $R_g = 6\Omega$	
Turn-Off Fall Time	t <sub>F</sub>	_	22	_		, and a second s	
Reverse Recovery Time	t <sub>RR</sub>	_	49.8	_	ns	1 400 11/11 4000/	
Reverse Recovery Charge	Q <sub>RR</sub>	_	85.1	_	nC	I <sub>F</sub> = 13A, di/dt = 100A/μs	

Notes:

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.6. Short duration pulse test used to minimize self-heating effect.7. Guaranteed by design. Not subject to product testing.





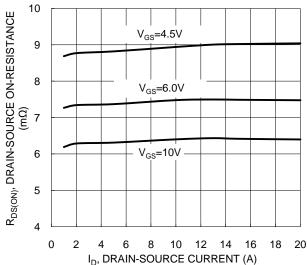


Figure 3. Typical On-Resistance vs. Drain Current

and Gate Voltage

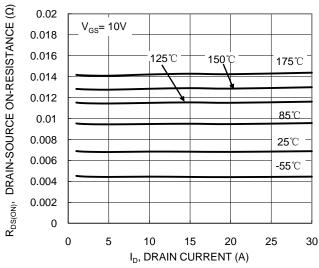
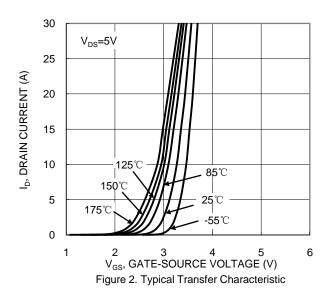
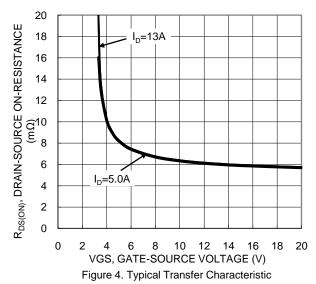


Figure 5. Typical On-Resistance vs Drain Current and Junction Temperature





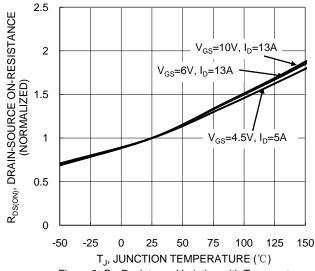


Figure 6. On-Resistance Variation with Temperature





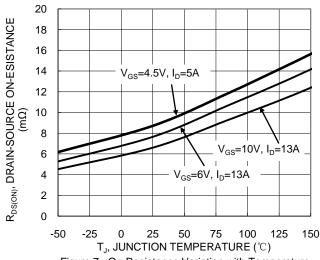
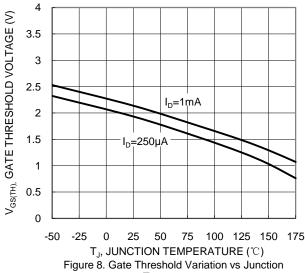


Figure 7. On-Resistance Variation with Temperature



Temperature

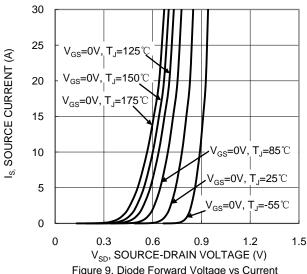
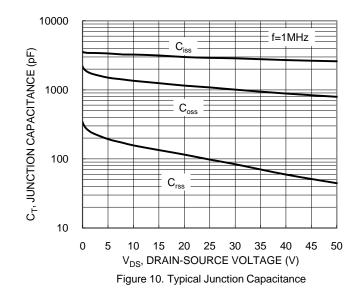
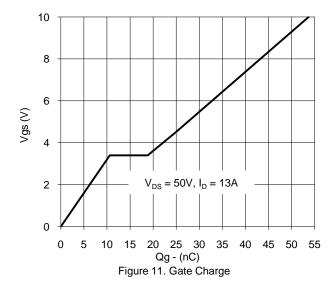
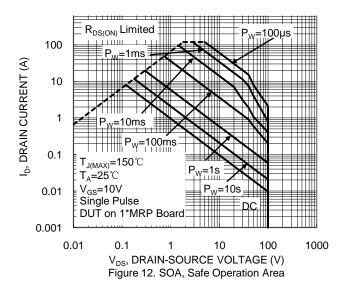


Figure 9. Diode Forward Voltage vs Current









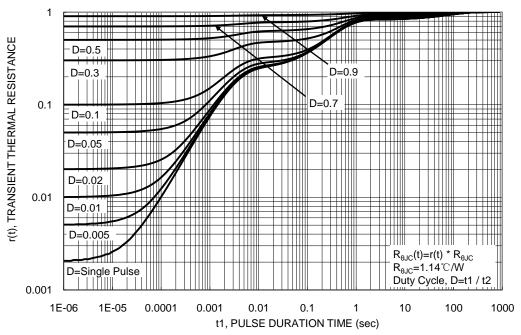


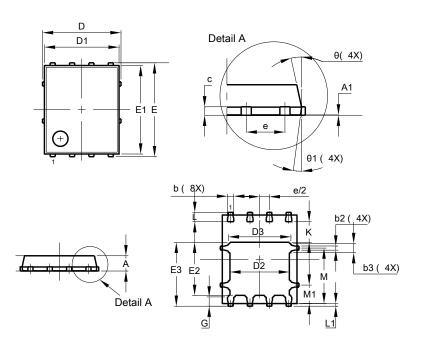
Figure 13. Transient Thermal Resistance



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8

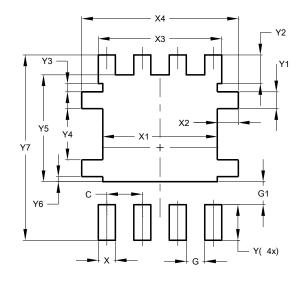


PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.00 0.05 -			
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D		5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
Е	(	6.15 BSC			
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е		1.27 BSC	;		
G	0.51	0.71	0.61		
K	0.51	_	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12º	11º		
Θ1	6°	8º	7º		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8



Dimensions	Value (in mm)			
C	1.270			
G	0.660			
G1	0.820			
Х	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Υ	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



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